

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3402 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

Low On-State Resistance

- ★ $R_{DS(on)1} = 15 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 18 \text{ A})$
- **★** RDS(on)2 = 22 m Ω MAX. (VGS = 4.0 V, ID = 18 A)
- ★ Low Ciss : Ciss = 3200 pF TYP.
 - Built-in Gate Protection Diode
 - TO-251/TO-252 package

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \ ^{\circ}C$)

Drain to Source Voltage	VDSS	60	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	D(DC)	±36	А
Drain Current (Pulse) Note1	D(pulse)	±144	А
Total Power Dissipation ($Tc = 25^{\circ}C$)	Pτ	40	W
Total Power Dissipation (TA = 25°C)	P⊤	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	35	А
Single Avalanche Energy Note2	Eas	123	mJ

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3402	TO-251		
2SK3402-Z	TO-252		



(TO-251)

(TO-252)



Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting T_{ch} = 25 °C, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

THERMAL RESISTANCE

Channel to Case	Rth(ch-C)	3.13	°C/W
Channel to Ambient	Rth(ch-A)	125	°C/W

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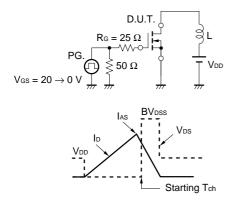
★ ELECTRICAL CHARACTERISTICS (TA = 25 °C)

NEC

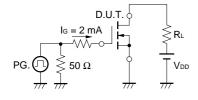
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 18 A		12	15	mΩ
	RDS(on)2	Vgs = 4.0 V, Id = 18 A		15	22	mΩ
Gate to Source Cut-off Voltage	VGS(off)	$V_{DS} = 10 V, I_{D} = 1 mA$	1.5	2.0	2.5	V
Forward Transfer Admittance	y _{fs}	Vds = 10 V, Id = 18 A	13	27		S
Drain Leakage Current	Ibss	Vds = 60 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 10 V		3200		pF
Output Capacitance	Coss	V _{GS} = 0 V		520		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		270		pF
Turn-on Delay Time	td(on)	ID = 18 A		36		ns
Rise Time	tr	$V_{GS(on)} = 10 V$		310		ns
Turn-off Delay Time	td(off)	Vdd = 30 V		170		ns
Fall Time	tr	Rg = 10 Ω		180		ns
Total Gate Charge	Q _G	ID = 36 A		61		nC
Gate to Source Charge	Q _{GS}	Vdd = 48 V		8.2		nC
Gate to Drain Charge	Qgd	V _{GS(on)} = 10 V		17		nC
Body Diode Forward Voltage	VF(S-D)	IF = 36 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 36 A, VGS = 0 V		48		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		89		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

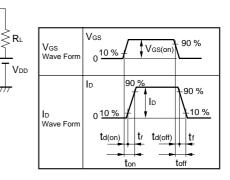
TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE



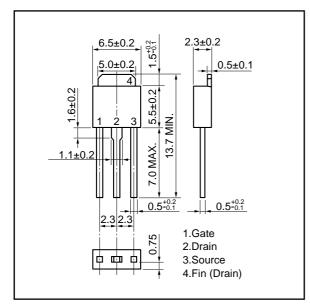
D.U.T. ١ΛΛ -0 Rg PG. Vgs 0 · τ $\tau = 1 \,\mu s$ Duty Cycle $\leq 1 \%$



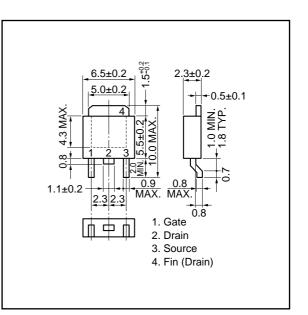
Preliminary Data Sheet D14473EJ1V0DS00

PACKAGE DRAWINGS (Unit : mm)

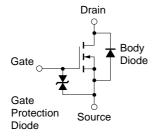
1) TO-251 (MP-3)



2) TO-252 (MP-3Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device. • The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

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